

Verify Regim for M_1 :

$$V_{DS_1} > \overbrace{V_{GS_1} - V_{THN}}^{V_{DS,sat}}$$

(Long-channel)
 $V_{DS,sat} = V_{GS} - V_{THN}$

$$V_{D_1} - \cancel{V_{S_1}} > V_{G_1} - \cancel{V_{S_1}} - V_{THN}$$

$$\Rightarrow V_{D_1} > V_{G_1} - V_{THN}$$

$$3.842 > \underbrace{2.5 - 0.8}_{1.7V}$$

yes, M_1 is in
Saturation

Assume M_4 is Triode:

$$V_{SD_4} = ?$$

$$I_D = K_P \frac{W}{L} \left[(V_{SG_4} - V_{THP}) \underbrace{V_{SD_4}}_x - \frac{V_{SD_4}^2}{2} \right]$$

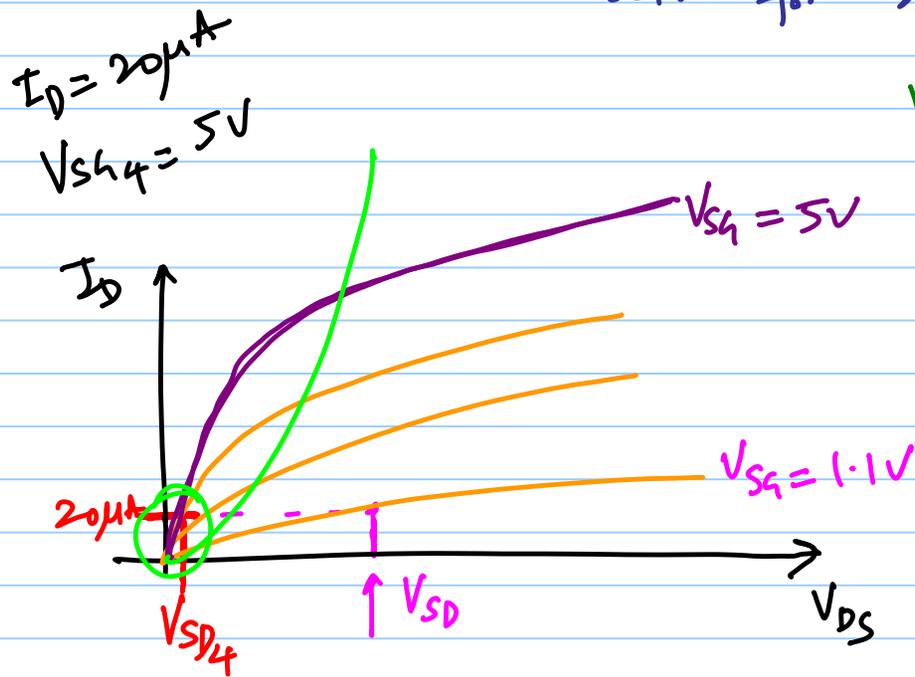
← ^{Current} Triode Equation

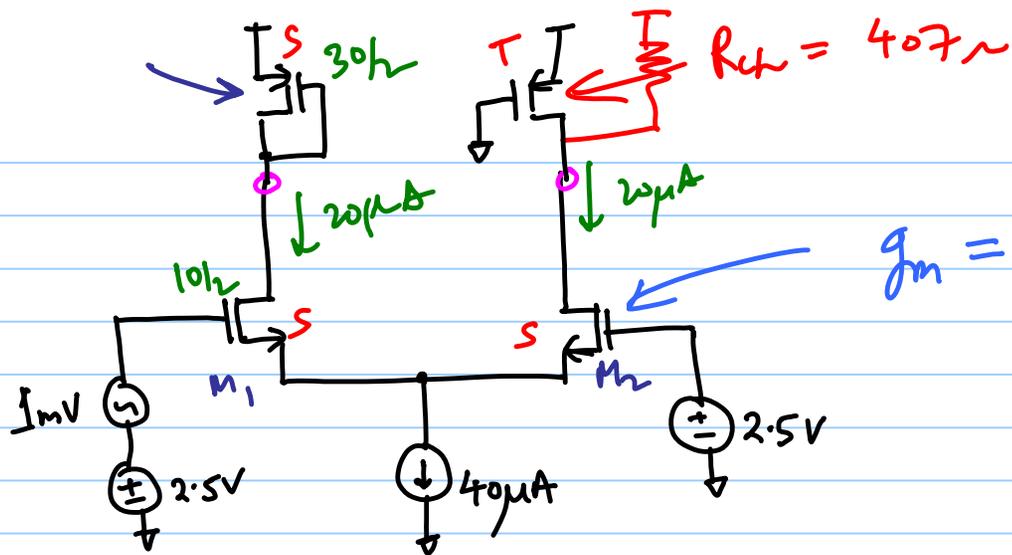
$$20\mu = 40\mu \cdot \frac{30}{2} \left[4 \cdot 1x - \frac{x^2}{2} \right]$$

solve for $x \leq 8.13 \text{ mV}$

TI-89
fsolve()

$$V_{D4} = 5V - V_{SD4} = 5 - 0.50813 = \boxed{4.992V}$$





$$g_m = \sqrt{2\beta I_D} = 150 \frac{\mu A}{V}$$

$$= \sqrt{2 \times k_p \frac{W}{L} \times 20\mu}$$

$$g_{m1,2} = 150 \frac{\mu A}{V}$$

$$g_{m3} = \sqrt{2 \times 40 \frac{\mu A}{V^2} \times \frac{30}{2} \times 20\mu} = \boxed{150 \frac{\mu A}{V}}$$

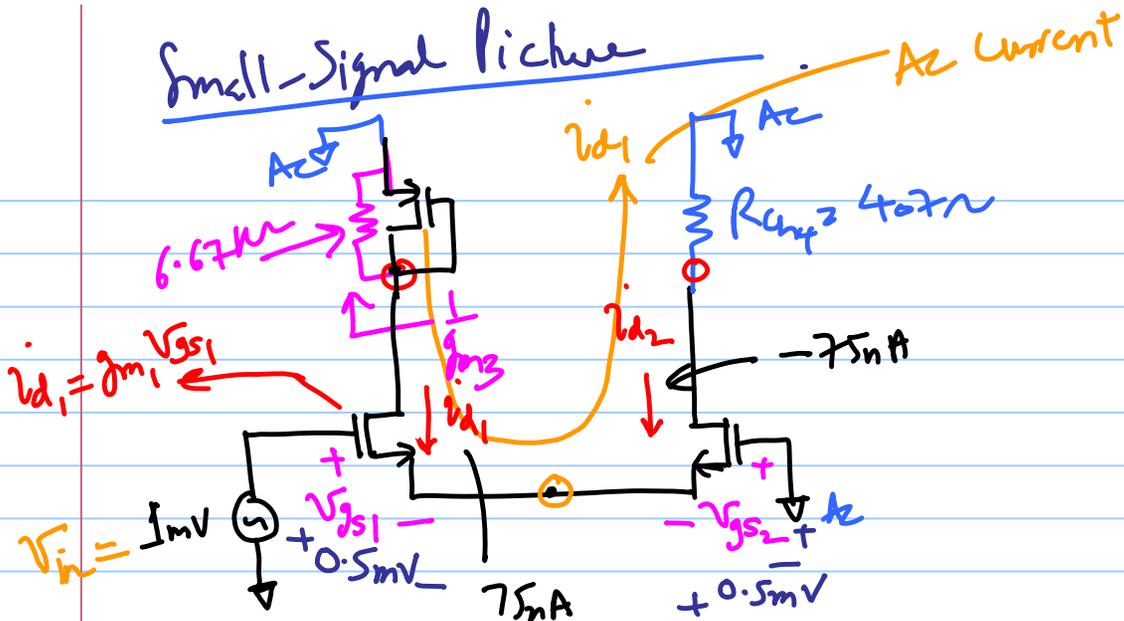
$$R_{ch4} = \frac{1}{k_p \frac{W}{L} (V_{sk} - V_{thp})} = \boxed{407\Omega}$$

$$\lambda \cdot \gamma_0 = \frac{1}{\lambda \cdot I_{D,sat}}$$

~ find from the $I_D - V_{DS}$

$$\lambda \cdot g_{m6} = (\lambda)' g_m$$

Small-Signal Picture



$$V_{in} = 1mV = V_{gs1} - V_{gs2} \rightarrow \textcircled{1}$$

$$i_{d1} + i_{d2} = 0$$

$$i_{d2} = -i_{d1} \rightarrow \textcircled{2}$$

$$g_{m2} V_{gs2} = -g_{m1} V_{gs1}$$

$$V_{gs2} = -V_{gs1} \rightarrow \textcircled{3}$$

plug $\textcircled{3}$ into $\textcircled{1}$

$$V_{gs1} - (-V_{gs1}) = 1mV$$

$$\begin{aligned} V_{gs1} &= 0.5mV \\ V_{gs2} &= -0.5mV \end{aligned}$$

$$i_{d1} = g_{m1} v_{gs1} = 150 \frac{\mu\text{A}}{\text{V}} \times 0.5 \text{ mV} = \boxed{75 \text{ nA}}$$

$$i_{d2} = -i_{d1} = \boxed{-75 \text{ nA}}$$

$$v_{d1} = -i_{d1} \times \frac{1}{g_{m3}} = \boxed{-0.5 \text{ mV}}$$

$$v_{d2} = -i_{d2} \times R_{44} = \boxed{0.03 \text{ mV}}$$

↑
-75 nA

Total

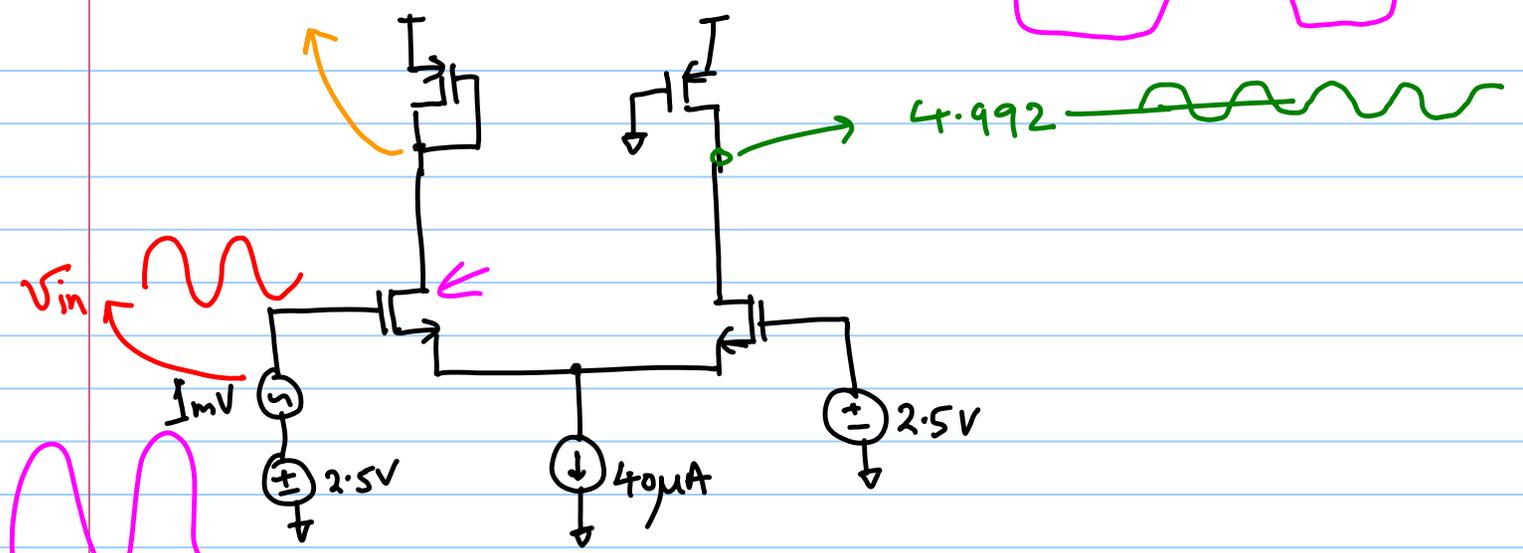
$$\begin{aligned} \dot{i}_{D_1} &= \overset{DC}{I_{D_1}} + \overset{AC}{i_{d_1}} \\ &= 20\mu A + (75nA) \sin(\omega_{int}) \end{aligned}$$

$$\dot{i}_{D_2} = 20\mu A - (75nA) \sin(\omega_{int})$$

$$v_{D_1,3} = \underbrace{3.842}_{DC} \underbrace{- 0.5 \times 10^{-3} \sin(\omega_{int})}_{AC}$$

$$v_{D_2,4} = 4.992 + 0.03 \times 10^{-3} \sin(\omega_{int})$$

3.842V



4.992

V_{in}

5mV

2.5V

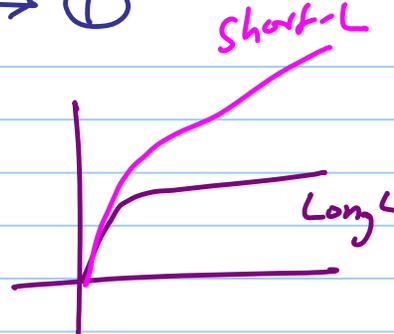
40μA

2.5V

$$I_{D,sat} = \frac{kn}{2} \frac{W}{L} \underbrace{(V_{GS} - V_{TH})}_{V_{OV}}^2 \longrightarrow \textcircled{1}$$

$$\lambda \propto \frac{1}{L} \longrightarrow \textcircled{2}$$

$$\gamma_0 \approx \frac{1}{\lambda I_{D,sat}} = \frac{1}{\lambda} \cdot \frac{L}{kn W V_{OV}^2}$$



from ① & ②

$$\gamma_0 \propto \frac{L^2}{V_{OV}^2}$$

Long-channel MOSFET

* for fixed Length

$$V_{OV} \uparrow \Rightarrow \gamma_0 \downarrow$$

* for fixed V_{OV}

$$L \downarrow \Rightarrow \gamma_0 \downarrow$$

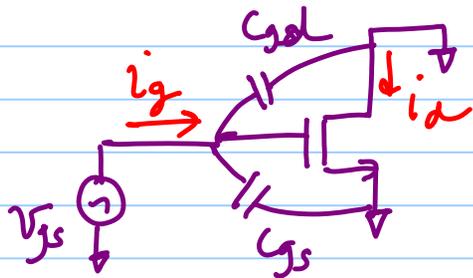
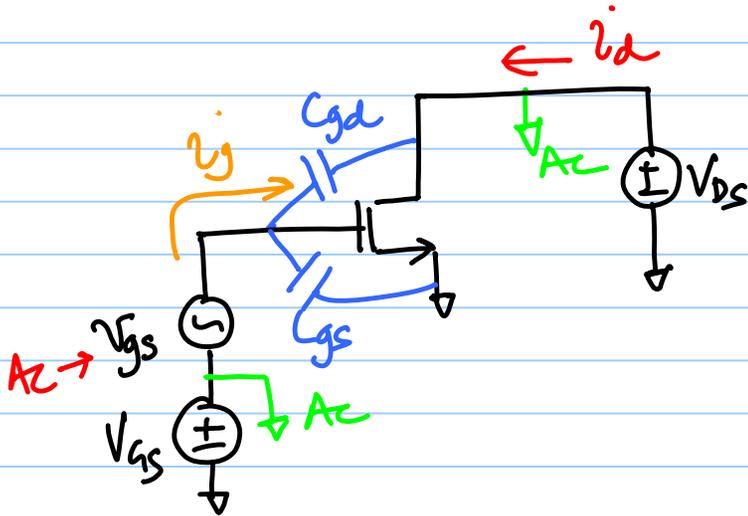
for fixed L , $V_{ov} \downarrow \Rightarrow \gamma_0 \uparrow$
But $\Rightarrow I_D \downarrow$

Transition frequency (f_T)

ITRS
Roadmap

f_T is the frequency where the AC current gain

$$@ f = f_T \Rightarrow \left| \frac{i_d}{i_g} \right| = 1 \text{ or } 0 \text{ dB}$$



$$v_{gs} = \frac{i_g}{s(C_{gd} + C_{gs})} \rightarrow \textcircled{1}$$

$$i_d = g_m v_{gs}$$

$$= \frac{g_m i_g}{s(C_{gd} + C_{gs})}$$

Current gain
in the MOSFET

$$\frac{i_d}{i_g} = \frac{g_m}{s(C_d + C_s)} \checkmark$$

$$s = j\omega$$

$$\left| \frac{i_d}{i_g}(j\omega) \right| = \left| \frac{g_m}{j\omega(C_d + C_s)} \right|$$

$$\left| \frac{i_d}{i_g} \right| = \frac{g_m}{\omega(C_d + C_s)} \stackrel{\checkmark}{\cong} 1$$

$$\omega_T = \frac{g_m}{C_d + C_s}$$

$$\text{or } \boxed{f_T = \frac{g_m}{2\pi(C_d + C_s)}} \quad \text{fT}$$

$$f_T = \frac{g_m}{2\pi(C_{gd} + C_{gs})} \rightarrow \frac{2}{3} C_{ox}' WL$$

↑
C_{GD0} · L

In saturation

$$f_T \approx \frac{g_m}{2\pi C_{gs}}$$

$$f_T \propto \frac{V_{ov}}{L^2}$$

